Dynamical structural instability and a new crystal-electronic structure of infinite-layer nickelates

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Abstract

We use first-principles calculations to find that in infinite-layer nickelates $\textit{RNiO}_2$, the widely studied tetragonal $P4/mmm$ structure is only dynamically stable for early lanthanide elements $R = \text{La-Sm}$. For late lanthanide elements $R = \text{Eu-Lu}$, an imaginary phonon frequency appears at $A = (\pi, \pi, \pi)$ point. For those infinite-layer nickelates, condensation of this phonon mode into the $P4/mmm$ structure leads to a more energetically favorable $I4/mcm$ structure that is characterized by an out-of-phase rotation of “NiO$_4$ square”. Special attention is given to two borderline cases: PmNiO$_2$ and SmNiO$_2$, in which both the $P4/mmm$ structure and the $I4/mcm$ structure are local minimums, and the energy difference between the two structures can be fine-tuned by epitaxial strain. Compared to the $P4/mmm$ structure, $\textit{RNiO}_2$ in the $I4/mcm$ structure has a substantially reduced Ni $d_{x^2-y^2}$ bandwidth, a smaller Ni $d$ occupancy, a “cleaner” Fermi surface with less contribution from lanthanide element $d$ orbitals, and a decreased critical $U_{\text{Ni}}$ to stabilize long-range antiferromagnetic ordering. All these features favor Mott physics and render $\textit{RNiO}_2$ in the $I4/mcm$ structure a closer analogy to superconducting infinite-layer cuprates.
I. INTRODUCTION

The discovery of superconductivity in infinite-layer nickelates Sr$_x$Nd$_{1-x}$NiO$_2$ [1] has drawn great attention [2–9] because the parent material NdNiO$_2$ has similar crystal and electronic structures to those of infinite-layer cuprate CaCuO$_2$ [10], which exhibits high-temperature unconventional superconductivity upon doping [11, 12]. Both NdNiO$_2$ and CaCuO$_2$ crystallize in a simple tetragonal $P4/mmm$ structure in which Ni (Cu) and O atoms form a flat “NiO$_4$ (CuO$_4$) square” [13–15]. The $P4/mmm$ crystal structure has only two degrees of freedom: lattice constants $a$ and $c$. As for the non-interacting electronic structure, first-principles calculations show that CaCuO$_2$ has only one Cu $d_{x^2-y^2}$-derived band that crosses the Fermi level, while NdNiO$_2$ has two bands crossing the Fermi level [16–20]. One is Ni $d_{x^2-y^2}$-derived band and the other band is derived from Nd $d$ orbitals and an interstitial $s$ orbital [21–23]. So far, the minimum theoretical model that is adequate to describe low-energy physics of infinite-layer NdNiO$_2$ has been under intensive debate and several different mechanisms for superconductivity in Sr$_x$Nd$_{1-x}$NiO$_2$ have been proposed [24–43]. Albeit there are many important differences, one thing that all the models have in common is the $P4/mmm$ crystal structure of NdNiO$_2$ (either experimental one or DFT optimized one), based on which one-particle band structure calculations [44–49] or more sophisticated many-body electronic structure calculations [50–62] are performed. On the experimental side, in addition to Sr$_x$Nd$_{1-x}$NiO$_2$, recently superconductivity is also observed in Sr$_x$Pr$_{1-x}$NiO$_2$ [63–65], Sr$_x$La$_{1-x}$NiO$_2$ [66] and Ca$_x$La$_{1-x}$NiO$_2$ [67, 68]. Thus it is anticipated that superconductivity should be observed in the entire lanthanide series of infinite-layer nickelates RNiO$_2$. In particular, Refs. [69, 70] perform a systematic study on the electronic structure trends of RNiO$_2$ as $R$ traverses the lanthanide series and RNiO$_2$ remains in the $P4/mmm$ structure.

In this work, we use first-principles calculations to show that the widely studied $P4/mmm$ structure of infinite-layer nickelates is only dynamically stable for early lanthanide elements $R = \text{La-Sm}$. For late lanthanide elements $R = \text{Eu-Lu}$, an imaginary phonon mode appears at $A = (\pi, \pi, \pi)$ point in the $P4/mmm$ structure of RNiO$_2$. The imaginary phonon mode corresponds to an out-of-phase rotation of “NiO$_4$ square” about the $z$ axis. Condensation of this unstable phonon mode into the $P4/mmm$ structure leads to a more energetically favorable crystal structure with lower symmetry (space
group $I4/mcm$). Attention is given to two borderline cases PmNiO$_2$ and SmNiO$_2$ which has two local minimums: the $P4/mmm$ structure and the $I4/mcm$ structure. Epitaxial strain can be used to fine-tune the energy difference between the two crystal structures.

Compared to the $P4/mmm$ structure of infinite-layer $R$NiO$_2$, in the new $I4/mcm$ structure, the Ni $d_{x^2-y^2}$ bandwidth is substantially reduced (by about 0.5 eV) and Ni $d$ occupancy also decreases; the Fermi surface becomes “cleaner” with less contribution from the $d$ orbitals of lanthanide element $R$; the critical $U_{Ni}$ to stabilize a long-range antiferromagnetic ordering in $R$NiO$_2$ is smaller. All these results show that with the “NiO$_4$ square” rotation, correlation effects will be enhanced and Mott physics will play a more prominent role in the new $I4/mcm$ structure than in the $P4/mmm$ structure, when local interaction is added on Ni $d$ orbitals [71]. In particular, our results suggest that among the lanthanide series of infinite-layer nickelates, SmNiO$_2$ is the most promising candidate to crystallize in the $I4/mcm$ structure, which renders it a closer analogy to superconducting infinite-layer cuprates and may favor superconductivity of higher transition temperature.

II. COMPUTATIONAL DETAILS

We perform density functional theory (DFT) [72, 73] calculations within the *ab initio* plane-wave approach, as implemented in the Vienna Ab-initio Simulation Package (VASP) [74, 75]. We use projected augmented wave (PAW) pseudopotentials with the 4$f$ electrons placed in the core (except for La), explicitly to avoid complication that arises from treating the localized 4$f$ electrons. We employ generalized gradient approximation (GGA) for the exchange-correlation functional with Perdew-Burke-Ernzerhof (PBE) parametrization [76]. The theoretical lattice constants of $R$NiO$_2$ are in good agreement with the available experimental structure information (see Appendix A) [15, 49, 77]. We use an energy cutoff of 600 eV. Charge self-consistent calculations are converged to $10^{-7}$ eV. Both cell and internal atomic positions are fully relaxed until each force component is smaller than 1 meV/Å and pressure on the cell is smaller than 0.1 kBar. We use the finite-displacement method to calculate the full phonon dispersion with the aid of Phonopy [78]. A supercell that consists of $3 \times 3 \times 3$ primitive cells is used to calculate the force constants and dynamical matrices. The primitive cell of the $P4/mmm$ structure has one formula of $R$NiO$_2$ (i.e. 4 atoms), while the primitive
cell of the $I4/mcm$ structure has two formulae of $R\text{NiO}_2$ (i.e. 8 atoms) in order to accommodate the rotation of “NiO$_4$ square”. For the 4-atom $P4/mmm$ cell, we use a Monkhorst-Pack $k$ mesh of $14 \times 14 \times 14$ to sample the first Brillouin zone. For the 8-atom $I4/mcm$ cell, we use a Monkhorst-Pack $k$ mesh of $10 \times 10 \times 10$ to sample the first Brillouin zone. For ease of comparison, when calculating the electronic structure, Fermi surface and long-range magnetic ordering, we use the 8-atom cell for both $P4/mmm$ and $I4/mcm$ structures. This cell-doubling is also necessary to accommodate the rocksalt antiferromagnetic ordering in the $P4/mmm$ structure. To break spin symmetry and study magnetic order, we use the charge-only DFT+$U$+$J$ method [79–81] (by setting LDAUTYPE = 4 in VASP). This method is such that the exchange-correlation functional only depends on charge density but not on spin density; thereby, spin symmetry is only broken by the $U/J$ terms that are added to the Kohn-Sham potential, while the exchange splitting that arises from the spin-dependent exchange-correlation functional is disabled. By setting the parameter $U/J = 0$ in the charge-only DFT+$U$+$J$ method, the non-spin-polarized DFT results are recovered. The calculations of Ni $d$ projected magnetic moment and Ni $d$ occupancy use the default VASP value for the radius of sphere which is 1.11 Å.

III. RESULTS

A. Phonon spectrum

We calculate the phonon dispersion of the fully-relaxed $P4/mmm$ structure for the entire lanthanide series of infinite-layer $R\text{NiO}_2$. We find that the complete set of phonon dispersions (see Appendix B) can be classified into four categories, which we use colors to distinguish in panel a. The first category includes $R=$La-Nd (denoted by green). NdNiO$_2$ is the prototype, whose full phonon dispersion is shown in panel b. In this category, the full phonon dispersion is free of imaginary modes and the $P4/mmm$ crystal structure is dynamically stable. The second category includes $R=$Pm, Sm (denoted by yellow). SmNiO$_2$ is the prototype, whose full phonon dispersion is shown in panel c. In this category, a soft phonon develops at $A = (\pi, \pi, \pi)$ point, implying a potentially unstable mode. The third category includes $R=$Eu-Dy (denoted by orange). EuNiO$_2$ is the prototype, whose full phonon dispersion is shown in panel d. In this category, the
Figure 1. Phonon properties of infinite-layer $R$NiO$_2$ in the $P4/mmm$ structure. a: The series of lanthanide elements. Different colors are used to distinguish four categories of phonon dispersions, whose prototypes are shown in b-e. b: Phonon dispersion of infinite-layer NdNiO$_2$ in the $P4/mmm$ structure. c: Phonon dispersion of infinite-layer SmNiO$_2$ in the $P4/mmm$ structure. d: Phonon dispersion of infinite-layer EuNiO$_2$ in the $P4/mmm$ structure. e: Phonon dispersion of infinite-layer TmNiO$_2$ in the $P4/mmm$ structure. f: Frequency of the lowest phonon mode at $A = (\pi, \pi, \pi)$ point $\omega^*_A$ for the entire lanthanide series of infinite-layer $R$NiO$_2$ in the $P4/mmm$ structure. g: The lowest phonon mode at $A$ point of infinite-layer $R$NiO$_2$ in the $P4/mmm$ structure.

The frequency of the lowest phonon mode at $A$ point (marked as $\omega^*_A$) becomes imaginary and the $P4/mmm$ crystal structure is dynamically unstable. The last category includes $R=$Ho-Lu (denoted by red). TmNiO$_2$ is the prototype, whose full phonon dispersion is shown in panel e. In this category, the lowest phonon modes at multiple $q$ points become imaginary in the phonon dispersion, indicating that the $P4/mmm$ crystal structure is far from stable. In panel f, we compare the frequency of the lowest phonon mode at $A$ point $\omega^*_A$ for the entire lanthanide series. We find that $\omega^*_A$ monotonically decreases from La to Lu and becomes imaginary when $R=$Eu and beyond. In panel g, we show the lowest phonon mode at $A$ point of the $P4/mmm$ structure, which is an out-of-
phase rotation of “NiO$_4$ square” about the $z$ axis. Infinite-layer nickelates with early lanthanide elements such as NdNiO$_2$ are stable against this “NiO$_4$ square” rotation, and their equilibrium structure is the widely-studied $P4/mmm$ structure. However, infinite-layer nickelates with late lanthanide elements become dynamically unstable when the “NiO$_4$ square” rotates. Condensation of this unstable mode into the $P4/mmm$ structure will lead to a more energetically favorable crystal structure, which in turn results in a new electronic structure.

B. Rotation of “NiO$_4$ square” and the new $I4/mcm$ structure

When the lowest phonon frequency at the $A$ point in the $P4/mmm$ structure of $R$NiO$_2$ becomes imaginary ($R =$ Eu-Lu), it means that condensation of this unstable phonon mode into the $P4/mmm$ structure can decrease the total energy and will result in a new crystal structure with lower symmetry. Such a crystal structure is shown in panel a of Fig. 2, which has space group $I4/mcm$. The primitive cell of the $I4/mcm$ structure has 8 atoms, which has three degrees of freedom: in addition to the two lattice constants $a$ and $c$, there is an angle $\theta$ that characterizes the out-of-phase rotation of “NiO$_4$ square” about the $z$ axis. When $\theta = 0$, the $I4/mcm$ structure is reduced to the $P4/mmm$ structure. For ease of comparison with the $I4/mcm$ structure, we show the two-Ni unit cell of the $P4/mmm$ structure (doubling the 4-atom primitive cell along the [111] direction) in panel b. For subsequent electronic structure, Fermi surface and long-range magnetic ordering calculations of infinite-layer $R$NiO$_2$, we use the 8-atom cell for both the $I4/mcm$ structure and the $P4/mmm$ structure.

To get a better understanding of the new $I4/mcm$ structure, we calculate the energy evolution of $R$NiO$_2$ as a function of the rotation angle $\theta$ (see panel c of Fig. 2). We select $R =$ Nd, Pm, Sm and Eu, which are near the phase boundary where the lowest phonon frequency at $A$ point becomes imaginary. We find that the total energy of NdNiO$_2$ monotonically increases with the rotation angle $\theta$, indicating that the $P4/mmm$ structure (i.e. $\theta = 0$) is stable against the rotation of “NiO$_4$ square”. By contrast, the total energy of EuNiO$_2$ first decreases with the rotation angle $\theta$ and then increases. The energy minimum is at $\theta = 7.7^\circ$. This clearly shows that the $P4/mmm$ structure is not dynamically stable in infinite-layer EuNiO$_2$. PmNiO$_2$ and SmNiO$_2$ (the second category) exhibit more interesting features in that they have two local
Figure 2.  

**a**: The primitive cell of infinite-layer nickelate $R\text{NiO}_2$ in the $I4/mcm$ structure. $\theta$ is the rotation angle of “NiO$_4$ square” along the $z$ axis. **b**: A doubled unit cell of infinite-layer nickelate $R\text{NiO}_2$ in the $P4/mnm$ structure (the $P4/mnm$ primitive cell is doubled along $[111]$ direction). $\theta = 0^\circ$ in the $P4/mnm$ structure. **c**: The energy evolution of $R\text{NiO}_2$ ($R =$ Nd, Pm, Sm and Eu) as a function of the “NiO$_4$ square” rotation angle $\theta$. The $P4/mnm$ structure is used as the energy reference. **d**: The zoom-in view of the energy evolution of PmNiO$_2$ and SmNiO$_2$ as a function of the “NiO$_4$ square” rotation angle $\theta$. **e** and **f**: The phonon dispersions of infinite-layer PmNiO$_2$ and SmNiO$_2$ in the $I4/mcm$ structure, respectively.

Minimums: one is at $\theta = 0^\circ$ ($P4/mnm$ structure) and the other is at $\theta > 0$ ($I4/mcm$ structure), as is shown in panel **d**. For PmNiO$_2$, the energy of the $P4/mnm$ structure is slightly lower than that of the $I4/mcm$ structure by 0.5 meV/f.u. For SmNiO$_2$, the energy order is reversed and the $I4/mcm$ structure becomes more stable than the $P4/mnm$ structure by 10.5 meV/f.u. Furthermore, we calculate the energy barrier from the $P4/mnm$ structure to the $I4/mcm$ structure. We find that the barrier de-
creases from 2.8 meV/f.u. for PmNiO$_2$ to 0.5 meV/f.u. for SmNiO$_2$. Next we test that after condensation of the “NiO$_4$ square” rotation mode, the $I4/mcm$ structure becomes dynamically stable in some infinite-layer nickelates. We perform the phonon calculation of the $I4/mcm$ structure for PmNiO$_2$ and SmNiO$_2$. The phonon dispersions are shown in panels e and f. We find that the phonon dispersion of the $I4/mcm$ structure is free from imaginary frequencies for PmNiO$_2$ and SmNiO$_2$. We make two comments here. First, while SmNiO$_2$ has two local minimums, considering the facts that 1) its $I4/mcm$ structure is energetically more favorable than the $P4/mmm$ structure, 2) the energy barrier for SmNiO$_2$ to transition from the $P4/mmm$ structure to the $I4/mcm$ structure is very small, and 3) its $I4/mcm$ structure is dynamically stable, we argue that SmNiO$_2$ is probably stabilized in the $I4/mcm$ structure. Second, the “NiO$_4$ square” rotation is the first structural distortion that will appear in the $P4/mmm$ structure of infinite-layer nickelates RNiO$_2$ when the lanthanide element $R$ traverses from La to Lu. For late lanthanide elements (such as Ho-Lu), more complicated structural distortions are expected to emerge in infinite-layer RNiO$_2$. The purpose of the current study is to show that just by including one more degree of freedom in the crystal structure of RNiO$_2$ (i.e. “NiO$_4$ square” rotation), the resulting electronic structure trends can be substantially different from those of the $P4/mmm$ structure. In particular, the new electronic structure and Fermi surface of SmNiO$_2$ in the $I4/mcm$ structure render it a closer analogy to superconducting infinite-layer cuprates (see discussion below).

C. Epitaxial strain

Before we carefully compare the physical properties between the $I4/mcm$ structure and the $P4/mmm$ structure, we study epitaxial strain effects first. That is because superconductivity in infinite-layer nickelates is observed in thin films rather than in bulk [1, 14]. We investigate how epitaxial strain influences the phonon dispersion of infinite-layer RNiO$_2$, in particular, whether it may remove the imaginary phonon mode at $A$ point and thus stabilize the $P4/mmm$ structure. Experimentally, oxide thin films are grown along the $z$ axis with a bi-axial strain imposed by substrates in the $xy$ plane. The bi-axial strain (either compressive or tensile) typically ranges within 3% [82].

Panel a of Fig. 3 shows the lowest phonon frequency at $A$ point $\omega_A$ of a few infinite-layer RNiO$_2$ in the $P4/mmm$ structure as a function of biaxial strain $\xi$. We select
Figure 3.  

**a**: The lowest phonon frequency at \( A = (\pi, \pi, \pi) \) point of infinite-layer \( RNiO_2 \) in the \( P4/mmm \) structure (\( R = \text{Pm, Sm, Eu and Gd} \)) as a function of biaxial strain. Negative (positive) strain means compressive (tensile) biaxial strain.  

**b** and **c**: The phonon dispersions of infinite-layer \( \text{SmNiO}_2 \) in the \( P4/mmm \) structure. The cyan curves are the phonon dispersions of fully-relaxed \( \text{SmNiO}_2 \) (i.e. without strain). The red curves in **b** and **c** are the phonon dispersions of \( \text{SmNiO}_2 \) under 1% and 2% compressive strains, respectively. The black arrows highlight that with compressive strain, the lowest phonon mode at \( A = (\pi, \pi, \pi) \) point is "hardened", while the lowest phonon modes at \( Z = (0, 0, \pi) \) and \( R = (\pi, 0, \pi) \) are "softened".  

**d**: The energy evolution of infinite-layer \( \text{SmNiO}_2 \) as a function of "NiO\(_4\) square" rotation angle \( \theta \). The red, cyan and green symbols correspond to 1% compressive strain, no strain and 1% tensile strain, respectively. For each case, the \( P4/mmm \) structure is used as the energy reference.

\( R = \text{Pm, Sm, Eu and Gd} \), which are close to the phase boundary where \( \omega^*_A \) becomes imaginary (the complete phonon dispersions of those four nickelates under epitaxial strain are found in Appendix C). The biaxial strain is defined as \( \xi = (a_{\text{sub}} - a)/a \times 100\% \), where \( a_{\text{sub}} \) is the theoretical substrate lattice constant and \( a \) is the DFT optimized lattice constant of infinite-layer \( RNiO_2 \) in the \( P4/mmm \) structure. For each infinite-layer \( RNiO_2 \), we vary the strain \( \xi \) and find that \( \omega^*_A \) decreases with tensile strain and
increases with compressive strain. However, we note that for infinite-layer nickelate GdNiO$_2$, a compressive strain up to 3% can not remove the “NiO$_4$ rotation” instability in the $P4/mmm$ structure. This is also true for other infinite-layer nickelates $R$NiO$_2$ with late lanthanide elements ($R$ = Gd-Lu). More importantly, we find that while compressive strain helps remove the phonon instability at $A$ point in the $P4/mmm$ structure, it may induce other phonon instabilities. Panel b compares the phonon dispersions of infinite-layer nickelate SmNiO$_2$ in the $P4/mmm$ structure under 1% compressive strain versus without epitaxial strain. It shows that compressive strain “hardens” the lowest phonon frequency at $A$ point but “softens” the lowest phonon frequencies at $Z$ and $R$ points. Under a compressive strain of 2% or larger (see panel c and Fig. 9), the lowest phonon frequencies at $Z$ and $R$ points become imaginary in the $P4/mmm$ structure. To summarize, for infinite-layer nickelates, tensile strain increases the phonon instability at $A$ point in the $P4/mmm$ structure; small compressive strain helps remove the phonon instability at $A$ point but larger compressive strain can cause other phonon instabilities at $Z$ and $R$ points. Hence, epitaxial strain alone cannot substantially increase the stability of the $P4/mmm$ structure in infinite-layer nickelates $R$NiO$_2$.

On the other hand, we find that for SmNiO$_2$, epitaxial strain can tune its energetics and structural properties. Panel d of Fig. 3 shows the energy evolution of SmNiO$_2$ as a function of “NiO$_4$ square” rotation angle $\theta$. We compare three different epitaxial strains: 1% compressive (-1%), no strain (0%) and 1% tensile (+1%). From 1% compressive strain to 1% tensile strain, the energy difference between the $I4/mcm$ structure and the $P4/mcm$ structure monotonically increases from 4.8 to 17.5 meV/f.u. in its magnitude (indicating that the $I4/mcm$ structure gradually becomes more stable than the $P4/mmm$ structure). At the same time, the energy barrier from the $P4/mmm$ structure to the $I4/mcm$ structure decreases from 1.5 meV/f.u. (1% compressive strain) to 0.5 meV/f.u. (no strain) and disappears (1% tensile strain). The disappearance of the energy barrier indicates that under 1% tensile strain, the $P4/mmm$ structure is no longer a local minimum in SmNiO$_2$ and it spontaneously transitions into the $I4/mcm$ structure. Furthermore, the equilibrium “NiO$_4$ square” rotation angle $\theta$ in the $I4/mcm$ structure also increases from 6.4$^\circ$ to 7.1$^\circ$ when the epitaxial strain changes from 1% compressive to 1% tensile strain. This shows that epitaxial strain can be used as a
fine-tuning knob to delicately control the structural stability of infinite-layer SmNiO$_2$.

In the next three sections, we will study the entire lanthanide series of infinite-layer nickelates in the $I\overline{4}/mcm$ structure and in the $P4/mmm$ structure. We compare the trends in electronic properties and magnetic properties between the two crystal structures. We focus on SmNiO$_2$ as a prototype.

D. $P4/mmm$ versus $I\overline{4}/mcm$ structures: structural properties

Fig. 4 compares the structural properties between the $I\overline{4}/mcm$ structure and the $P4/mmm$ structure. For infinite-layer nickelates in the first category ($R =$ La-Nd), we only study the $P4/mmm$ structure because the $I\overline{4}/mcm$ structure cannot be stabilized in those nickelates. In panel a, we calculate the “NiO$_4$ square” rotation angle $\theta$. In the $P4/mmm$ structure, $\theta = 0^\circ$ by definition. We find that in the $I\overline{4}/mcm$ structure, $\theta$ increases as we traverse from Pm to Lu. A finite $\theta$ means that the in-plane Ni-O-Ni
bond angle is reduced from the ideal 180°. Panels b and c show the lattice constants a and c of the I4/mcm and P4/mmm structures. For ease of comparison to the P4/mmm structure, we convert the lattice constants of the I4/mcm structure into the pseudotetragonal lattice constants a and c. While the general trend is similar in the two structures that a and c get smaller when R traverses the lanthanide series, we find that for a given R, the a and c lattice constants are larger in the I4/mcm structure than in the P4/mmm structure. Panel d shows the volume per Ni atom of the I4/mcm and P4/mmm structures. We find that the volume decreases more slowly in the I4/mcm structure than in the P4/mmm structure. For a given R, if RNiO2 is stabilized in the I4/mcm structure, the Ni-O bond length gets longer and the Ni-O hopping becomes smaller due to the larger volume and the reduced Ni-O-Ni bond angle, compared to the P4/mmm structure. These features will have important influences on the electronic structures.

E. P4/mmm versus I4/mcm structures: electronic properties

Panel a of Fig. 5 compares the Ni d_{x^2−y^2} bandwidth of the I4/mcm structure and the P4/mmm structure. Consistent with the previous studies [69, 70], the Ni d_{x^2−y^2} bandwidth of the P4/mmm structure monotonically increases when R traverses the lanthanide series. That is because the volume of the P4/mmm structure monotonically decreases, which increases the Ni-O hopping and thus the bandwidth. By stark contrast, we find that the Ni d_{x^2−y^2} bandwidth of the I4/mcm structure monotonically decreases when R traverses the lanthanide series. That is precisely due to the “NiO4 square” rotation θ in the I4/mcm structure, which competes with the volume effect. When the lanthanide element R changes from La to Lu, θ increases (see Fig. 4a). This reduces the Ni-O-Ni bond angle and thus suppresses the Ni-O hopping [83]. This effect, which is absent in the P4/mmm structure, counteracts the volume reduction and dominates in the I4/mcm structure. A similar picture of these two competing forces is also found in LiNbO3 under hydrostatic pressure [84]. As a consequence, the Ni d_{x^2−y^2} bandwidth of RNiO2 in the I4/mcm structure decreases across the lanthanide series. More importantly, for a given lanthanide element R, the Ni d_{x^2−y^2} bandwidth of the I4/mcm structure is substantially smaller than that of the P4/mmm structure. For example, for SmNiO2, its Ni d_{x^2−y^2} bandwidth is 3.2 eV in the P4/mmm structure and
is reduced to 2.7 eV in the $I4/mcm$ structure. This indicates that for the same value of $U$ on Ni $d_{x^2-y^2}$ orbital, correlation effects are enhanced in the $I4/mcm$ structure, compared to the $P4/mmm$ structure. In addition, we also compare the Ni $d$ orbital occupancy $N_d$ between the $I4/mcm$ structure and the $P4/mmm$ structure in panel b. $N_d$ has been used as a key parameter to characterize the $p$-$d$ hybridization and correlation strength in complex oxides [85]. We find that for a given lanthanide element $R$, $N_d$ is smaller in the $I4/mcm$ structure than in the $P4/mmm$ structure. A smaller $N_d$ corresponds to a smaller critical $U$ value for the metal-insulator transition [85], i.e. $R$NiO$_2$ in the $I4/mcm$ structure is closer to the Mott insulating phase than that in the $P4/mmm$ structure.

Next we focus on SmNiO$_2$ and study its electronic band structure and Fermi surface (very similar results are also obtained in infinite-layer nickelates close to the phase boundary $R$NiO$_2$ with $R =$ Pm, Eu and Gd, see Appendix D). Panels c and d show the electronic band structure of SmNiO$_2$ in the $P4/mmm$ structure and in the $I4/mcm$ structure, respectively. We find that in the $P4/mmm$ structure, there are four bands that cross the Fermi level: two are Ni-$d_{x^2-y^2}$ derived bands and the other two are Sm-$d$ derived bands. However, in the $I4/mcm$ structure, there are only three bands that cross the Fermi level: two Ni-$d_{x^2-y^2}$ derived bands and only one Sm-$d$ derived band. This renders the electronic structure of $I4/mcm$ SmNiO$_2$ closer to that of infinite-layer CaCuO$_2$. Furthermore, we compare the Fermi surface of SmNiO$_2$ in the $P4/mmm$ structure and in the $I4/mcm$ structure (panels e and f, respectively). We find that in the body-centered tetragonal first Brillouin zone of the $P4/mmm$ structure [70], there are two $\Gamma$-centered electron pockets that are derived from Sm-$d$ bands. By comparison, in the first Brillouin zone of the $I4/mcm$ structure, one $\Gamma$-centered electron pocket disappears, which is consistent with the fact that one Sm-$d$ derived band is removed from the Fermi level (panel d). Hence, compared to the $P4/mmm$ structure, the Fermi surface of SmNiO$_2$ in the $I4/mcm$ structure more closely resembles that of CaCuO$_2$.

F. $P4/mmm$ versus $I4/mcm$ structures: magnetic properties

Next we compare the magnetic properties of $R$NiO$_2$ between the $I4/mcm$ structure and the $P4/mmm$ structure. We use the charge-only DFT+$U$+$J$ method [79–81] in which the spin polarization is broken by the $U/J$ extension rather than the spin-
Figure 5. Electronic properties of infinite-layer nickelates RNiO$_2$ in the $I4/mcm$ structure and in the $P4/mmm$ structure. a and b: bandwidth of Ni $d_{x^2-y^2}$ orbital and Ni $d$ occupancy. The blue (black) symbols refer to the $I4/mcm$ structure (the $P4/mmm$ structure). c and d: Electronic structure of SmNiO$_2$ in the $P4/mmm$ structure and in the $I4/mcm$ structure, respectively. The red (blue) symbols highlight the atomic projection onto the Ni $d_{x^2-y^2}$ orbital (Sm $d$ orbitals). e and f: Fermi surface of SmNiO$_2$ in the $P4/mmm$ structure and in the $I4/mcm$ structure, respectively. The red (blue) arrows highlight the Fermi surface sheets that are composed of Ni $d_{x^2-y^2}$ orbital (Sm $d$ orbitals).
Figure 6. Magnetic properties of infinite-layer nickelates $R\text{NiO}_2$ in the $I4/mcm$ structure (blue symbols) and in the $P4/mmm$ structure (black symbols). a: The magnetic moment on Ni atom of SmNiO$_2$ in rocksalt antiferromagnetic ordering (AFM) as a function of $U_{\text{Ni}}$. b: The critical $U_{\text{Ni}}$ for rocksalt antiferromagnetic ordering across the lanthanide series of infinite-layer nickelates $R\text{NiO}_2$. c: The energy difference between rocksalt antiferromagnetic ordering and ferromagnetic ordering of SmNiO$_2$ as a function of $U_{\text{Ni}}$. The dashed lines highlight the critical $U_{\text{Ni}}$ for rocksalt antiferromagnetic ordering. d: The energy difference between rocksalt antiferromagnetic ordering and ferromagnetic ordering at $U_{\text{Ni}} = 3$ eV across the lanthanide series of infinite-layer nickelates $R\text{NiO}_2$.

dependent exchange-correlation functional. The advantage of using this method is that when $U/J$ parameters approach zero, we will recover our non-spin-polarized DFT results.

We first study rocksalt antiferromagnetic ordering (ordering wave vector $\mathbf{q} = (\pi, \pi, \pi)$) in SmNiO$_2$. Panel a of Fig. 6 shows the magnetic moment on Ni atom as a function of $U_{\text{Ni}}$ (throughout the calculations, we set $J_{\text{Ni}} = 0.15U_{\text{Ni}}$ [86]). We compare the Ni magnetic moment between the $I4/mcm$ structure and the $P4/mmm$ structure. We find that the critical $U_{\text{Ni}}$ for rocksalt antiferromagnetic ordering is reduced from 1.8 eV in the $P4/mmm$ structure to 1.5 eV in the $I4/mcm$ structure. This is consistent with the bandwidth reduction effect that correlation strength is increased
on Ni $d_{x^2-y^2}$ orbital in the $I4/mcm$ structure, which favors the formation of long-range magnetic ordering. Next in panel b, we study the entire lanthanide series of infinite-layer nickelates $RNiO_2$ and compare the critical $U_{Ni}$ for the $I4/mcm$ structure and for the $P4/mmm$ structure. We find that the critical $U_{Ni}$ for the $I4/mcm$ structure is always smaller than that for the $P4/mmm$ structure, and from PmNiO$_2$ to LuNiO$_2$, the reduction in the critical $U_{Ni}$ becomes more substantial. This feature is consistent with the trend of Ni $d_{x^2-y^2}$ bandwidth reduction (see Fig. 5a). In addition, we study the energy difference between rocksalt antiferromagnetic ordering and ferromagnetic ordering $\Delta E = E_{AFM} - E_{FM}$ as a function of $U_{Ni}$. Panel c shows that for SmNiO$_2$, both in the $I4/mcm$ structure and in the $P4/mmm$ structure, when $U_{Ni}$ exceeds the critical value (highlighted by the two dashed lines), rocksalt antiferromagnetic ordering has lower energy than ferromagnetic ordering ($\Delta E$ is negative). However, the magnitude of $|\Delta E|$ is larger in the $I4/mcm$ structure than in the $P4/mmm$ structure when the long-range magnetic order is formed in SmNiO$_2$. This energy difference $\Delta E$ (both sign and magnitude) may be used as a very rough estimation of nearest-neighbor magnetic exchange [17, 46, 49]. The results in panel c imply that given the same value of $U_{Ni}$, qualitatively the estimated nearest-neighbor magnetic exchange increases from the $P4/mmm$ structure to the $I4/mcm$ structure. We repeat the same calculations for the entire lanthanide series of infinite-layer nickelates $RNiO_2$ and show in panel d the energy difference $\Delta E$ at $U_{Ni} = 3$ eV. We find that $\Delta E$ is negative and its magnitude is larger in the $I4/mcm$ structure than in the $P4/mmm$ structure for the entire series of $RNiO_2$ ($R = $ Pm-Lu).

IV. DISCUSSION

In the preceding section, we use the charge-only DFT+$U$+$J$ method to study magnetic properties. We fix the optimized crystal structure that is obtained from the non-spin-polarized (nsp) DFT calculations, upon which the electronic structure calculations are performed. This is the convention of some previous DFT+$U$ and DFT+dynamical mean field theory (DFT+DMFT) studies [45–47, 53–58, 70]. In this section, we study relaxation effects on the magnetic properties of infinite-layer nickelates in the $I4/mcm$ and $P4/mmm$ structures. Within the charge-only DFT+$U$+$J$ method, we can relax the crystal structure for each given $U$ and $J$ (see Appendix E). We find that adding
$U$ and $J$ terms does not considerably change the optimized lattice constants and the “NiO$_4$ square” rotation angle. However, it is noted that a weak “cusp” feature emerges at the critical $U_{\text{Ni}}$ when the long-range magnetic ordering is stabilized. Using the optimized crystal structure from the charge-only DFT+$U$+$J$ method, we still find that 1) the critical $U_{\text{Ni}}$ for the $I4/mcm$ structure is smaller than that for the $P4/mmm$ structure, 2) rocksalt-antiferromagnetic ordering is more stable than ferromagnetic ordering in both crystal structures, and 3) the magnitude of the energy difference between rocksalt-antiferromagnetic ordering and ferromagnetic ordering is larger in the $I4/mcm$ structure than in the $P4/mmm$ structure. All these results are consistent with the previous ones that are obtained by using the nsp-DFT optimized crystal structure.

Another point that we want to note is that all the above results are about pristine infinite-layer nickelates $R$NiO$_2$, with an emphasis on SmNiO$_2$. In the experiment, superconductivity emerges when $R$NiO$_2$ is hole doped with the lanthanide element $R$ being partially substituted with an alkaline earth element (such as Sr or Ca) [63–68]. A natural question is whether this chemical substitution may also affect the crystal structure. A comprehensive first-principles study of random-alloying at an arbitrary doping concentration is challenging [87]. We argue that to achieve homogeneous alloying, one usually chooses two elements whose ionic sizes are similar. This helps stabilize the original crystal structure of the host material [88]. As a concrete example, we study Sr$_{0.25}$Sm$_{0.75}$NiO$_2$ whose crystal structure, phonon band structure, electronic band structure and Fermi surface are shown in Appendix F. We find that with 25% Sr doping in $I4/mcm$ SmNiO$_2$, the “NiO$_4$ square” rotation about the $z$ axis is still present in the optimized crystal structure. The phonon dispersion is free of imaginary modes, indicating that the optimized crystal structure is dynamically stable. The resulting electronic structure is similar to pristine SmNiO$_2$ in the $I4/mcm$ structure in that the majority of the Fermi surface is composed of Ni $d_{x^2-y^2}$ orbital with an additional electron pocket at $\Gamma$ point that is derived from Sm $d$ orbitals.

V. CONCLUSION

In conclusion, we perform first-principles calculations to study both structural and electronic properties of the entire lanthanide series of infinite-layer nickelates $R$NiO$_2$. We find that the widely-studied $P4/mmm$ structure is only dynamically stable when
$R$ is an early lanthanide element (La-Sm). For late lanthanide elements, when $R = \text{Eu}$ to Dy, an unstable phonon mode appears at $A$ point in the $P4/mmm$ structure, and when $R = \text{Ho}$ to Lu, more unstable phonon modes emerge at $A$, $Z$ and $R$ points in the $P4/mmm$ structure. The unstable phonon mode at $A$ point corresponds to an out-of-phase “NiO$_4$ square” rotation about the $z$ axis. For infinite-layer nickelates with late lanthanide elements, condensation of this phonon mode in the $P4/mmm$ structure lowers the total energy and leads to a new $I4/mcm$ crystal structure. Special attention is paid to two borderline cases PmNiO$_2$ and SmNiO$_2$, in which both the $P4/mmm$ structure and the $I4/mcm$ structure are local minimums. When epitaxial strain is imposed on infinite-layer nickelates, tensile strain further increases the dynamical instability at $A$ point in the $P4/mmm$ structure, while compressive strain “hardens” the phonon at $A$ point but “softens” the phonons at $Z$ and $R$ points in the $P4/mmm$ structure. Furthermore, epitaxial strain can fine-tune the energy difference between the $I4/mcm$ structure and the $P4/mmm$ structure when they are both dynamically stable in $R$NiO$_2$ (such as SmNiO$_2$).

We use the new $I4/mcm$ crystal structure to study the trends of electronic and magnetic properties in $R$NiO$_2$ and focus on SmNiO$_2$ as a prototype. We find that compared to the $P4/mmm$ structure, the Ni $d_{x^2-y^2}$ bandwidth of $R$NiO$_2$ is substantially reduced in the $I4/mcm$ structure, which implies an increased correlation strength in the new $I4/mcm$ structure. In addition, the Ni $d$ occupancy of $R$NiO$_2$ gets smaller in the $I4/mcm$ structure than that in the $P4/mmm$ structure, which means a small critical $U_{\text{Ni}}$ for the metal-insulator transition [85]. Furthermore, the electronic structure and Fermi surface of $R$NiO$_2$ become “cleaner” in the $I4/mcm$ structure than in the $P4/mmm$ structure, because one lanthanide $d$-orbital-derived band is removed from the Fermi level. Finally, the critical $U_{\text{Ni}}$ to stabilize the rocksalt antiferromagnetic ordering in $R$NiO$_2$ is reduced from the $P4/mmm$ structure to the $I4/mcm$ structure. All these results mean that Mott physics plays a more important role in the new $I4/mcm$ crystal structure of infinite-layer $R$NiO$_2$. Hence, if $R$NiO$_2$ in the $I4/mcm$ crystal structure can be synthesized in the experiment, it will provide a closer analogy to infinite-layer cuprate CaCuO$_2$. Our work suggests that among the lanthanide series of infinite-layer nickelates, the most promising candidate to crystallize in the $I4/mcm$ structure is SmNiO$_2$. 

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From a more general perspective of structure-property relations, controlling the rotation of “NiO₄ square” provides a new tuning knob to tailor the electronic and magnetic properties of infinite-layer RNiO₂. In perovskite oxides, transition metal atoms are encaged in an oxygen octahedron whose rotations and tilts have been intensively studied, which turn out to have important influences on physical properties of complex oxides [89–93]. Our work shows that in infinite-layer RNiO₂, by substituting the lanthanide element R, we can trigger the rotation of “NiO₄ square”, which tunes the underlying electronic structure and may potentially increase the superconducting transition temperature.
Appendix A: Comparison of DFT-optimized and experimental lattice constants

In this section, we compare DFT-optimized and experimental lattice constants of LaNiO$_2$, PrNiO$_2$ and NdNiO$_2$, which all crystallize in the $P4/mmm$ structure.

Table I. DFT-optimized and experimental lattice constants of LaNiO$_2$, PrNiO$_2$ and NdNiO$_2$ in the $P4/mmm$ structure.

<table>
<thead>
<tr>
<th></th>
<th>DFT-optimized</th>
<th>Experimental [77]</th>
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<tbody>
<tr>
<td></td>
<td>$a$ (Å)</td>
<td>$c$ (Å)</td>
</tr>
<tr>
<td>LaNiO$_2$</td>
<td>3.94</td>
<td>3.40</td>
</tr>
<tr>
<td>PrNiO$_2$</td>
<td>3.92</td>
<td>3.35</td>
</tr>
<tr>
<td>NdNiO$_2$</td>
<td>3.91</td>
<td>3.31</td>
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</tbody>
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Appendix B: Phonon spectrum of infinite-layer nickelates in the $P4/mmm$ structure

In this section, we show the complete set of phonon dispersions of the entire lanthanide series of infinite-layer nickelates $R\text{NiO}_2$ in the $P4/mmm$ structure.

Figure 7. Phonon dispersion of the entire rare-earth series of infinite-layer $R\text{NiO}_2$ ($R = \text{La-Lu}$) in the $P4/mmm$ structure.
Appendix C: Phonon spectrum of the $P4/mmm$ structure under epitaxial strain

In this section, we show the phonon dispersions of a few infinite-layer nickelates $R\text{NiO}_2$ under biaxial strain. We select PmNiO$_2$ (Fig. 8), SmNiO$_2$ (Fig. 9), EuNiO$_2$ (Fig. 10) and GdNiO$_2$ (Fig. 11), which are close to the $P4/mmm$-$I4/mcm$ phase boundary. The phonon dispersion is calculated in the $P4/mmm$ structure with the strain imposed. The biaxial strain is defined as $\xi = (a_{\text{sub}} - a)/a \times 100\%$, where $a_{\text{sub}}$ is the theoretical substrate lattice constant and $a$ is the DFT optimized lattice constant of infinite-layer $R\text{NiO}_2$ in the $P4/mmm$ structure.

Figure 8. Phonon dispersion of infinite-layer nickelate PmNiO$_2$ in the $P4/mmm$ structure under different biaxial strains. A positive (negative) strain means tensile (compressive) strain.
Figure 9. Phonon dispersion of infinite-layer nickelate SmNiO$_2$ in the $P4/mmm$ structure under different biaxial strains. A positive (negative) strain means tensile (compressive) strain.

Figure 10. Phonon dispersion of infinite-layer nickelate EuNiO$_2$ in the $P4/mmm$ structure under different biaxial strains. A positive (negative) strain means tensile (compressive) strain.
Figure 11. Phonon dispersion of infinite-layer nickelate GdNiO$_2$ in the $P4/mmm$ structure under different biaxial strains. A positive (negative) strain means tensile (compressive) strain.
Appendix D: Electronic properties of PmNiO$_2$, EuNiO$_2$, GdNiO$_2$ in $P4/mmm$ and $I4/mcm$ structures

In this section, we show the electronic structures and Fermi surfaces of PmNiO$_2$(Fig. 12), EuNiO$_2$(Fig. 13) and GdNiO$_2$(Fig. 14). We compare those electronic properties between the $P4/mmm$ structure and the $I4/mcm$ structure.

Figure 12.  a and b: Electronic structure of PmNiO$_2$ in the $P4/mmm$ structure and in the $I4/mcm$ structure, respectively. The red (blue) symbols highlight the atomic projection onto the Ni $d_{x^2-y^2}$ orbital (Pm $d$ orbitals).  c and d: Fermi surface of PmNiO$_2$ in the $P4/mmm$ structure and in the $I4/mcm$ structure, respectively. The red (blue) arrows highlight the Fermi surface sheets that are composed of Ni $d_{x^2-y^2}$ orbital (Pm $d$ orbitals).
Figure 13.  

**a** and **b**: Electronic structure of EuNiO$_2$ in the $P4/mmm$ structure and in the $I4/mcm$ structure, respectively. The red (blue) symbols highlight the atomic projection onto the Ni $d_{x^2-y^2}$ orbital (Eu $d$ orbitals).  

**c** and **d**: Fermi surface of EuNiO$_2$ in the $P4/mmm$ structure and in the $I4/mcm$ structure, respectively. The red (blue) arrows highlight the Fermi surface sheets that are composed of Ni $d_{x^2-y^2}$ orbital (Eu $d$ orbitals).
Figure 14.  a and b: Electronic structure of GdNiO$_2$ in the $P4/mmm$ structure and in the $I4/mcm$ structure, respectively. The red (blue) symbols highlight the atomic projection onto the Ni $d_{x^2-y^2}$ orbital (Gd $d$ orbitals). c and d: Fermi surface of GdNiO$_2$ in the $P4/mmm$ structure and in the $I4/mcm$ structure, respectively. The red (blue) arrows highlight the Fermi surface sheets that are composed of Ni $d_{x^2-y^2}$ orbital (Gd $d$ orbitals).
Appendix E: Structural and magnetic properties of fully-relaxed SmNiO$_2$

In this section, we show how atomic relaxation within the charge-only DFT+$U$+$J$ method may affect structural and magnetic properties of infinite-layer nickelates. We study SmNiO$_2$ in the $P4/mmm$ and $I4/mcm$ structures as a representative example. For each $U$ and $J$, we fully relax the crystal structure of SmNiO$_2$ with the space group symmetry imposed. Blue (black) symbols refer to the results of the $I4/mcm$ structure (the $P4/mmm$ structure). Panels a-d of Fig. 15 show the DFT-optimized structural properties of SmNiO$_2$ as a function of $U_{Ni}$: lattice constant $a$ (panel a), lattice constant $c$ (panel b), volume per formula (panel c) and “NiO$_4$ square” rotation angle $\theta$ (panel d). Panel e shows Ni magnetic moment of SmNiO$_2$ in rocksalt antiferromagnetic ordering as a function of $U_{Ni}$. Panel f shows the energy difference between rocksalt antiferromagnetic ordering and ferromagnetic ordering of SmNiO$_2$ as a function of $U_{Ni}$.

Figure 15. SmNiO$_2$ in the $I4/mcm$ structure (blue symbols) and in the $P4/mmm$ structure (black symbols). Both crystal structures are optimized using the charge-only DFT+$U$+$J$ method for each given $U$ and $J$ values. a: Lattice constant $a$. b: Lattice constant $c$. c: Volume per formula. d: “NiO$_4$ square” rotation angle $\theta$. e: The Ni magnetic moment of SmNiO$_2$ in rocksalt antiferromagnetic ordering (AFM). f: The energy difference between rocksalt antiferromagnetic ordering and ferromagnetic ordering of SmNiO$_2$. 

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Appendix F: Structural and electronic properties of Sr doped SmNiO$_2$

In this section, we study 25% Sr doped SmNiO$_2$. We use a supercell calculation. Panel a of Fig. 16 shows the optimized crystal structure of Sr$_{0.25}$Sm$_{0.75}$NiO$_2$, which exhibits a rotation of “NiO$_4$ square” about the $z$ axis in the presence of Sr substitution. Panel b shows the phonon spectrum of Sr$_{0.25}$Sm$_{0.75}$NiO$_2$, which is free of imaginary phonon frequencies. Panels c and d show the electronic band structure and Fermi surface of Sr$_{0.25}$Sm$_{0.75}$NiO$_2$, respectively. The Fermi surface is mainly composed of Ni $d_{x^2-y^2}$ orbital with an additional electron pocket centered around Γ point that derives from Sm $d$ orbitals.

Figure 16. Structural and electronic properties of Sr$_{0.25}$Sm$_{0.75}$NiO$_2$. a: Crystal structure. b: Phonon dispersion. c: Electronic band structure. d: Fermi surface.


